

UT30-35C12

SCR



VOLTAGE: 1200 Volts

CURRENT: 30 Amperes

Package: TO-220C

FEATURES

- Highly dv/dt For High Reliability
- Low Thermal Resistance Increases Carrying Capacity
- Strong resistance To Electromagnetic Interference.
- With High Ability To Withstand The Shock Loading Of Large Current

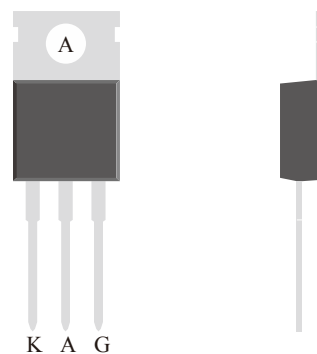
TYPICAL APPLICATIONS

- Phase Control Operation Of Light Dimmers And Motor Speed Controllers
- ON/OFF Control Operation Of Heating Regulation And Induction Motor

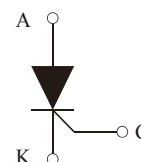
PRODUCT SUMMARY

Gear	Value	Unit
I_{GT}Max.	35	mA
V_{DRM}/V_{RRM} Min.	1200	V
I_{T(RMS)}	30	A

Diagram:



Polarity:



Absolute Maximum Ratings (Ta=25°C Unless otherwise specified)

Parameter	Test Conditions	Symbol	Ratings	Unit
Repetitive Peak Off-State Voltage		V_{DRM}	1200	V
Repetitive Peak Reverse Voltage		V_{RRM}	1200	V
RMS On-State Current	Tc≤ 40 °C	I_{T(RMS)}	30	A
Average On-State Current	Tc≤ 40 °C	I_{T(AV)}	20	
Non Repetitive Surge Peak On-State Current	F= 50 Hz, Tp= 10 ms	I_{TSM}	300	A
	F= 60 Hz, Tp= 8.3 ms		329	
I ² T Value For Fusing	Tp= 10 ms	I²t	450	A
Critical Rate Of Rise Of On-State Current	IG=2*IGT, tr≤100ns	di/dt	50	A/μs
	F= 100 Hz, Tj= 125 °C			
Peak Gate Current	Tp= 20 μs, Tj= 125 °C	I_{GM}	4	A
Average Gate Power Dissipation	Tj= 125 °C	P_{G(AV)}	1.0	W
Peak Gate Power Dissipation		P_{GM}	20	W
Maximum Mounting Torque	M3 screw	T_{MM}	1.1	N.m

Thermal Characteristics (Ta=25°C Unless otherwise specified)

Parameter	Test Conditions	Symbol	Typ.	Unit
Operating Junction Temperature Range		T_J	-40 to 125	°C
Storage Temperature Range		T_{STD}	-40 to 150	
Thermal Resistance Junction To Ambient With Steady-State	Still Air Environment With Ta=25°C	R_{θJA}	60	°C/W
Thermal Resistance Junction-Case With Steady-State	Device Mounted On 75mm x 45mm x 2.5mm Alu. Heat.	R_{θJC}	0.9	

UT30-35C12

SCR
Electrical Characteristics (Ta=25°C Unless otherwise specified)

Parameter	Test Conditions	Symbol	Value			Unit
			Min.	Typ.	Max.	
Gate Trigger Current	$V_D=12V, R_L=140\Omega$	I_{GT}	-	-	35.0	mA
Max. Gate Trigger Voltage	$V_D=12V, R_L=140\Omega$	V_{GT}	-	-	1.3	V
Min. Gate Trigger Voltage	$V_D=V_{DRM}, T_j=125^\circ C, R_L=3.3K\Omega$	V_{GD}	0.2	-	-	V
Holding Current	$I_T=500\text{ mA}$	I_H	-	-	120.0	mA
Latching Current	$I_G=1.2*I_{GT}$	I_L	-	-	180.0	mA
Rise Of Off- State Voltage	$V_D=2/3V_{DRM}, T_j=125^\circ C, \text{Gate Open}$	dv/dt	500.0	-	-	V/us

Static Characteristics (Ta=25°C Unless otherwise specified)

Parameter	Test Conditions	Symbol	Value	Unit
Peak On-State Voltage	$I_T=55\text{ A}, T_p=380\mu S, T_j=25^\circ C$	$V_{TM} M_{AX.}$	1.65	V
Threshold Voltage	$T_j=125^\circ C$	$V_{TO} M_{AX.}$	0.70	V
Peak Repetitive Forward Blocking Current	$V_D=V_{DRM}, T_j=25^\circ C$	$I_{DRM} M_{AX.}$	20	uA
Peak Repetitive Reverse Blocking Current	$V_R=V_{RRM}, T_j=125^\circ C$	$I_{RRM} M_{AX.}$	4	mA

Model and identification instructions

Product Type	UT	30	-	35.	C	12
UT=SCR						
Insulation Spec.:						
A=Ins.=Insulation						
Empty=No Ins.=No Insulation						
$I_{T(RMS)}$ Spec.:						
30=30A						
"- "=Connection Symbol						
Constant And Unchanging						
IGT Spec.						
35.=35mA						
Package Spec.:						
C=TO-220C						
VDRM/VRRM Spec.:						
12=1200V						
Temperature Spec.:						
Empty=Standard Temperature						
H=high temperature						

UT30-35C12

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Typical Characteristics Curves

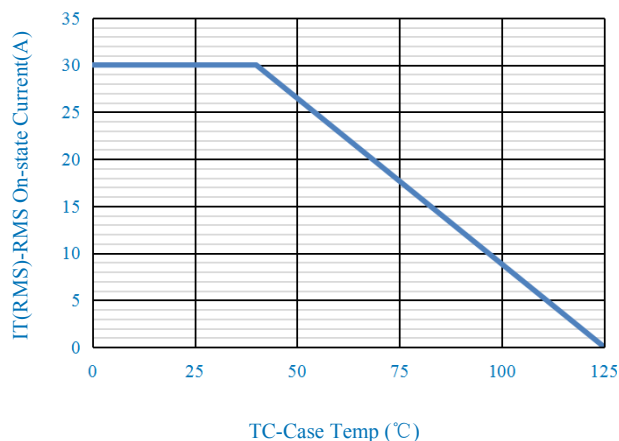


Fig.1-RMS on-state current vs. case temperature

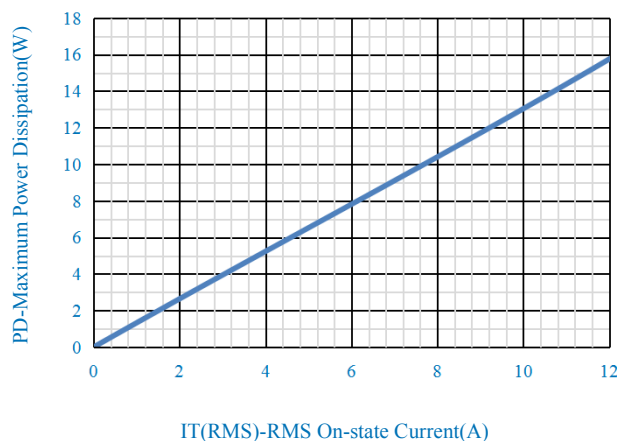


Fig.2- Maximum Power Dissipation Vs. on-state current

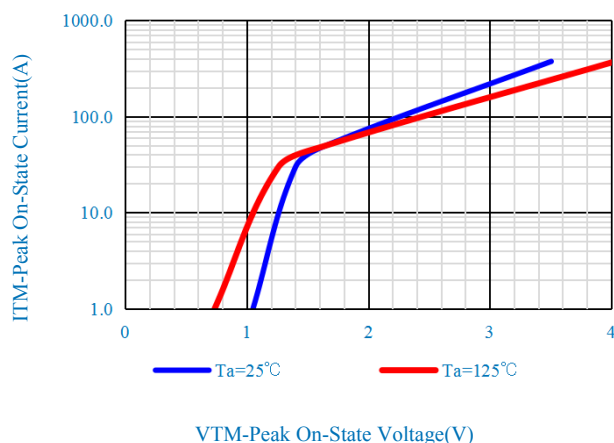


Fig.3-On-State Characteristics

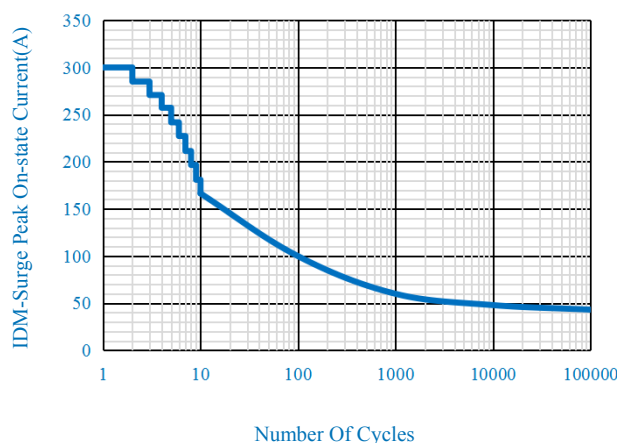


Fig.4- Surge Peak On-state Current Vs. Number Cycles

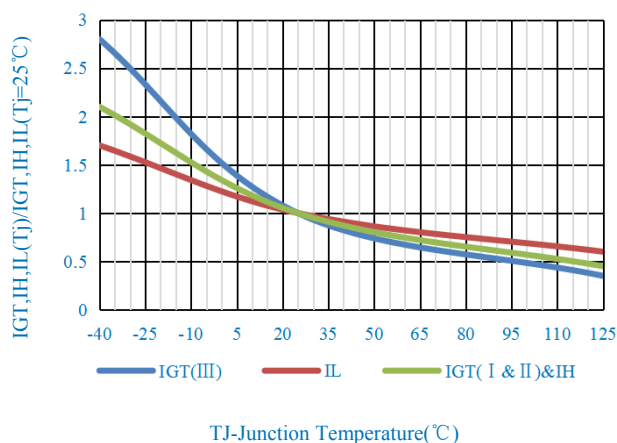


Fig.5- Relative Variation Of Gate Trigger Current , Holding Current And Latching Current Versus Junction Temperature (Typical Value)

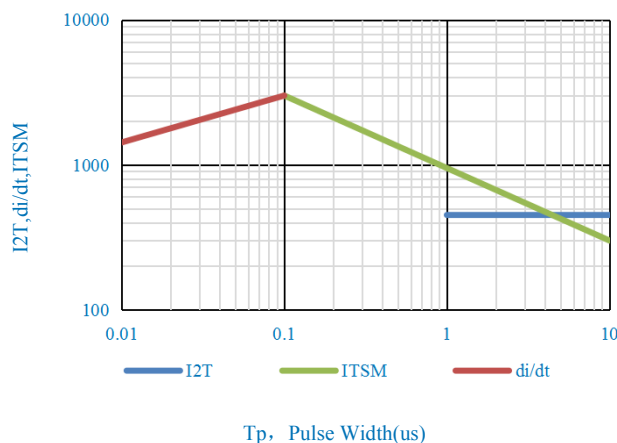
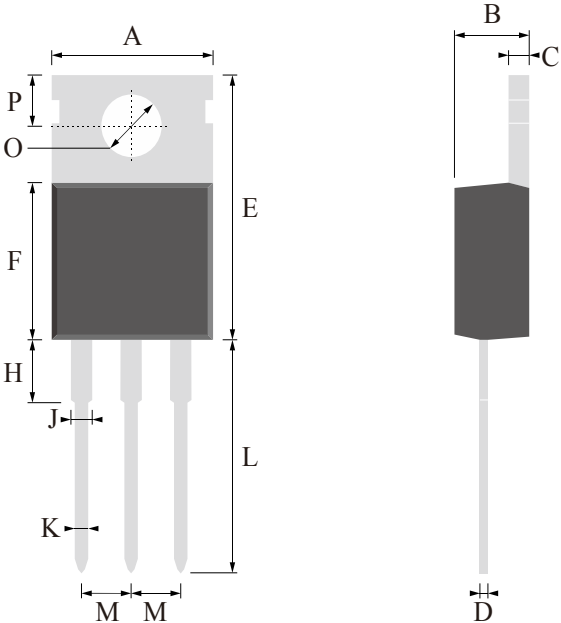


Fig.6- Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I_2t ($dI/dt < 50\text{A}/\mu\text{s}$)

UT30-35C12
SCR



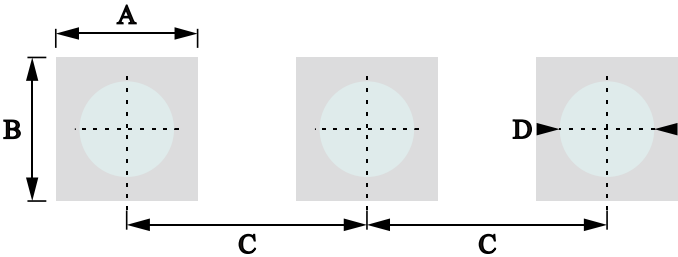
OUTLINE DRAWINGS



TO-220C

OUTLINE DIMENSIONS						
Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.25	-	10.75	0.3642	-	0.4232
B	4.15	-	4.95	0.1634	-	0.1949
C	1.10	-	1.65	0.0433	-	0.0650
D	0.25	-	0.65	0.0098	-	0.0256
E	14.50	-	16.70	0.5709	-	0.6575
F	8.40	-	9.95	0.3307	-	0.3917
L	12.15	-	14.30	0.4783	-	0.5630
H	3.00	-	3.80	0.1181	-	0.1496
J	1.05	-	1.60	0.0413	-	0.0630
K	0.65	-	0.95	0.0256	-	0.0374
M	2.10	-	2.90	0.0827	-	0.1142
O	3.20	-	4.10	0.1260	-	0.1614
P	2.45	-	3.10	0.0965	-	0.1220

RECOMMEDND LAYOUT DRAWINGS



TO-220C

OUTLINE DIMENSIONS						
Dim.	Milimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	-	1.60	-	-	0.0630	-
B	-	1.60	-	-	0.0630	-
C	-	2.54	-	-	0.1000	-
D	-	1.00	-	-	0.0394	-

UT30-35C12

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MARKING INFORMATION



MARKING INSTRUCTIONS

NH=Niuhang Trademark
FF=Product Line Code,According To Actual Changes
YWW=Date Code,According To Actual Changes
LLWWF=Inernal Code,According To Actual Changes
UT30-35C12=Model

PACKING INFORMATION

Package Type	Package Code	Product Weight Approx(g/Pcs)	Package Method	Quantity (Pcs/Min. Pack.)	Quantity (Pcs/Inner Box)	Quantity (Pcs/Carton)
TO-220C	P1	2.057	Tube	50	1000	5000

UT30-35C12

SCR



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow

	Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
	Average ramp-up rate (T _{smax} to T _p)	3°C/second max.	3°C/second max.
	Preheat-Temperature Min (T _S min) -Temperature Max (T _S max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
	Time maintained above: -Temperature (T _L) - Time (t _L)	183°C 60-150 seconds	217°C 60-150 seconds
	Peak Temperature(T _P)	240 +0/-5 °C	260 +0/-5 °C
	Time within 5°C of actual peak temperature (tp)	10-30 seconds	20-40 seconds
	Ramp down rate	6°C/second max.	6°C/second max.
	Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

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UT30-35C12



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Specification Revision History

Rev.	Date	Changed Items	Pre-Changed Content	Changed Content
A/1	2014-10-20	First Issue		
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